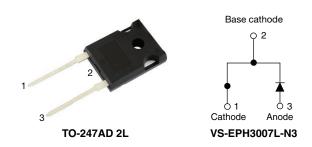
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# Hyperfast Rectifier, 30 A FRED Pt®



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	30 A								
V <sub>R</sub>	650 V								
V <sub>F</sub> at I <sub>F</sub>	1.4 V								
t <sub>rr</sub> typ.	33 ns								
T <sub>J</sub> max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

### FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V <sub>RRM</sub>		650	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 113 °C	30	^						
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 8.3 ms, half sine wave	195	A						
Operating junction and storage temperatures	TJ, T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	650	-	-				
Forward valtage	V <sub>F</sub>	I <sub>F</sub> = 30 A	- 1.8 2.1		V				
Forward voltage		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.4	1.6				
	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	0.02	30				
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μA			
Junction capacitance	CT	V <sub>R</sub> = 650 V	-	22	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \degree C$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, dI_F/dt = 100$	) Α/μs, V <sub>R</sub> = 30 V	-	37	-				
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	33	-	ns A			
		T <sub>J</sub> = 125 °C		-	88	-				
Dook rooovon ourront	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 30 A dl <sub>F</sub> /dt = 1000 A/µs	-	18	-				
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	30	-	A			
Deverse weeks weeks	0	T <sub>J</sub> = 25 °C		-	450	-	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1350	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.7	1.1	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-					
Weight			-	5.5	-	g				
Weight			-	0.2	-	oz.				
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)				
Marking device		Case style TO-247 2L		EPH	3007L					



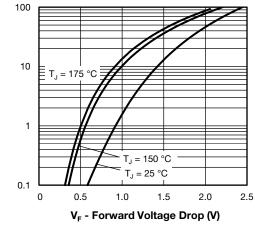


Fig. 1 - Typical Forward Voltage Drop Characteristics

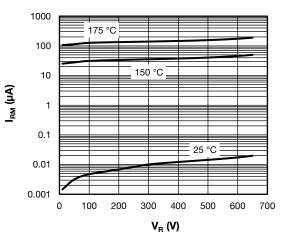


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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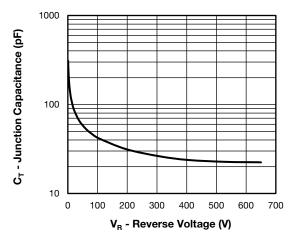


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

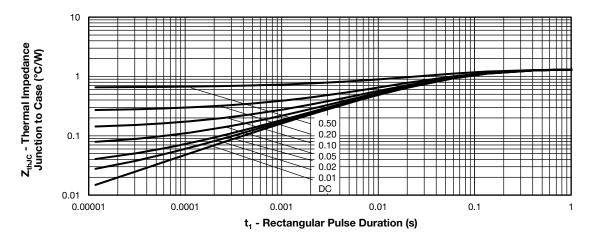
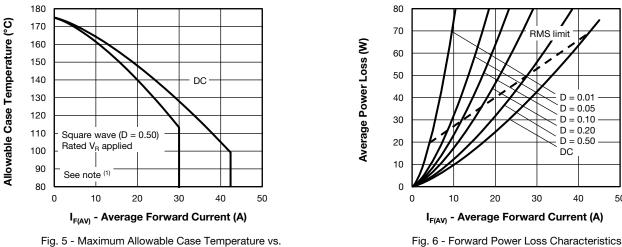


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



Average Forward Current

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3

50

**RMS** limit

D = 0.01

D = 0.05

D = 0.10

D = 0.20

D = 0.50

40

DC

30

20

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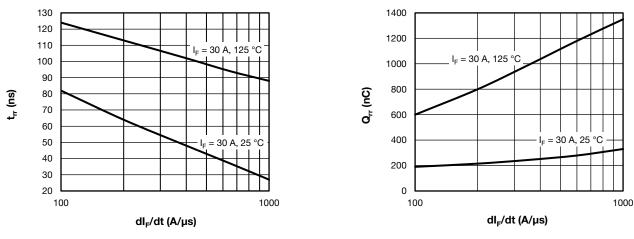
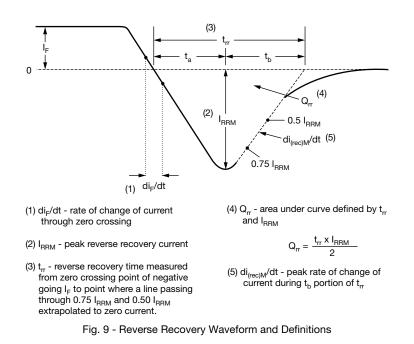


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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#### **ORDERING INFORMATION TABLE**

Device code	VS-	E	Р	н	30	07	L	-N3
								l
	(1)	(2)	(3)	(4)	(5)	6	(7)	(8)
	$\bigcirc$	Ŀ	U	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$
	1 -	· Visł	nay Sem	niconduc	tors pro	oduct		
	2 -	- E=	single c	liode				
	3 -	. P=	TO-247	,				
		-						
	4 -	• H=	hyperfa	st recov	ery time	Э		
	5 -	Cur	rent cod	le (30 =	30 A)			
	6 -	Volt	age coo	le (07 =	650 V)			
	<b>7</b> .		long lea	, d				
		L -	long loo	iu ii				
	8 -	- Env	rironmer	ntal digit	:			
		-N3	= halog	en-free,	RoHS-	complia	nt and t	totally le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-EPH3007L-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95536						
Part marking information	www.vishay.com/doc?95648						



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**TO-247AD 2L** 

#### **DIMENSIONS** in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIN	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053				•		•		•

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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